ISP815X, ISP825X, ISP845X
ISP815, ISP825, ISP845

HIGH DENSITY MOUNTING PHOTODARLINGTON OPTICALLY COUPLED ISOLATORS

APPROVALS

- UL recognised, File No. E91231

'X' SPECIFICATION APPROVALS

- VDE 0884 approval pending
- Certified to EN60950 by the following Test Bodies :-
  Nemko - Certificate No. P96102022
  Fimko - Registration No. 192313-01..25
  Semko - Reference No. 9639052 01
  Demko - Reference No. 305969

DESCRIPTION

The ISP815, ISP825, ISP845 series of optically coupled isolators consist of infrared light emitting diodes and NPN silicon photodarlingtons in space efficient dual in line plastic packages.

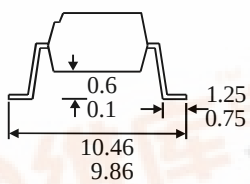
FEATURES

- Options :-
  10mm lead spread - add G after part no.
  Surface mount - add SM after part no.
  Tape&reel - add SMT&R after part no.
- High Current Transfer Ratio (600%min)
- High Isolation Voltage (5.3kV$_{RMS}$,7.5kV$_{PK}$)
- All electrical parameters 100% tested
- Custom electrical selections available

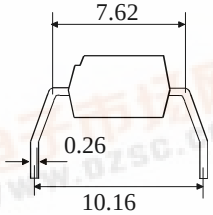
APPLICATIONS

- Computer terminals
- Industrial systems controllers
- Measuring instruments
- Signal transmission between systems of different potentials and impedances

OPTION SM
SURFACE MOUNT

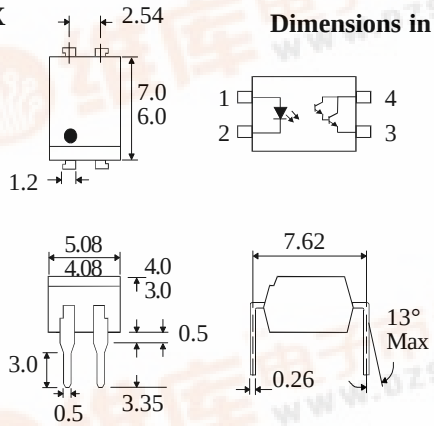


OPTION G

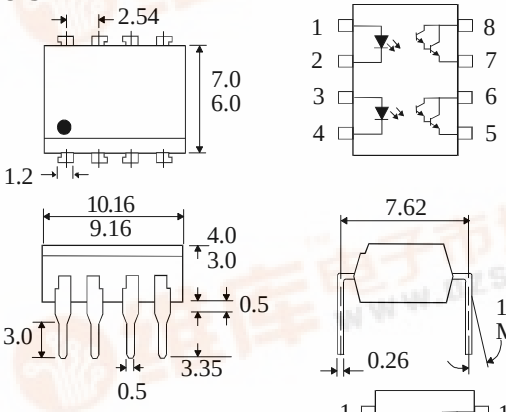


ISP815X
ISP815

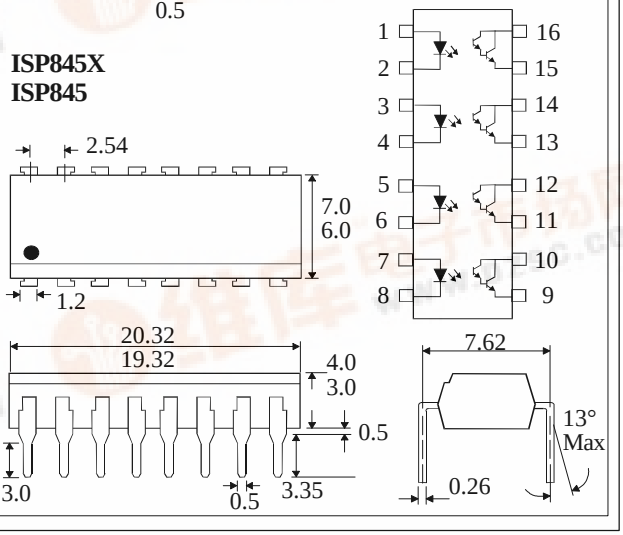
Dimensions in mm



ISP825X
ISP825



ISP845X
ISP845



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Tel: (01429) 863609 Fax :(01429) 863581

ABSOLUTE MAXIMUM RATINGS
(25°C unless otherwise specified)

Storage Temperature	-55°C to + 125°C
Operating Temperature	-55°C to + 100°C
Lead Soldering Temperature (1/16 inch (1.6mm) from case for 10 secs)	260°C

INPUT DIODE

Forward Current	50mA
Reverse Voltage	6V
Power Dissipation	70mW

OUTPUT TRANSISTOR

Collector-emitter Voltage BV_{CEO}	35V
Emitter-collector Voltage BV_{ECO}	6V
Power Dissipation	150mW

POWER DISSIPATION

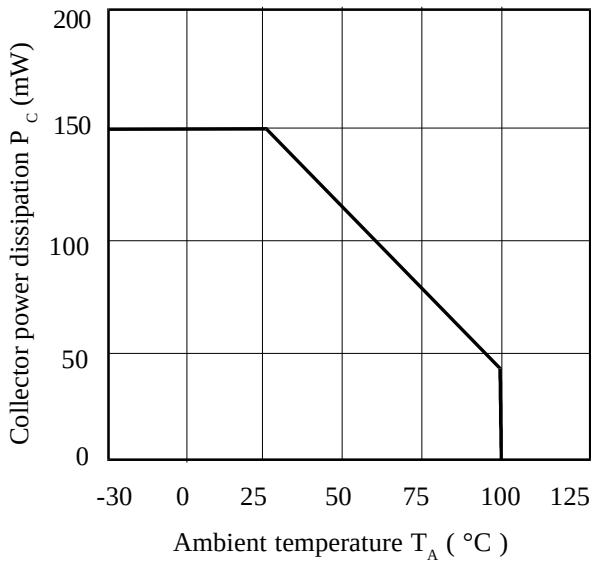
Total Power Dissipation	200mW
(derate linearly 2.67mW/°C above 25°C)	

ELECTRICAL CHARACTERISTICS (T_A = 25°C Unless otherwise noted)

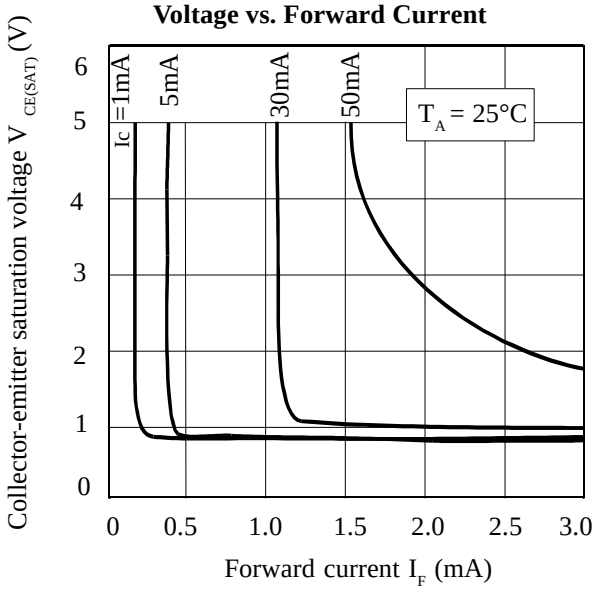
PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage (V_F)		1.2	1.4	V	I_F = 20mA
	Reverse Voltage (V_R)	6			V	I_R = 10µA
	Reverse Current (I_R)			10	µA	V_R = 6V
Output	Collector-emitter Breakdown (BV_{CEO}) (Note 2)	35			V	I_C = 1mA
	Emitter-collector Breakdown (BV_{ECO})	6			V	I_E = 100µA
	Collector-emitter Dark Current (I_{CEO})			100	nA	V_{CE} = 20V
Coupled	Current Transfer Ratio (CTR) (Note 2)	600		7500	%	1mA I_F, 2V V_{CE}
	Collector-emitter Saturation Voltage $V_{CE\ (SAT)}$			1.0	V	20mA I_F, 5mA I_C
	Input to Output Isolation Voltage V_{ISO}	5300 7500			V_{RMS} V_{PK}	See note 1 See note 1
	Input-output Isolation Resistance R_{ISO}	$5x10^{10}$			Ω	V_{IO} = 500V (note 1)
	Output Rise Time tr		60	300	µs	V_{CE} = 2V ,
	Output Fall Time tf		53	250	µs	I_C = 10mA, R_L = 100Ω

Note 1 Measured with input leads shorted together and output leads shorted together.
Note 2 Special Selections are available on request. Please consult the factory.

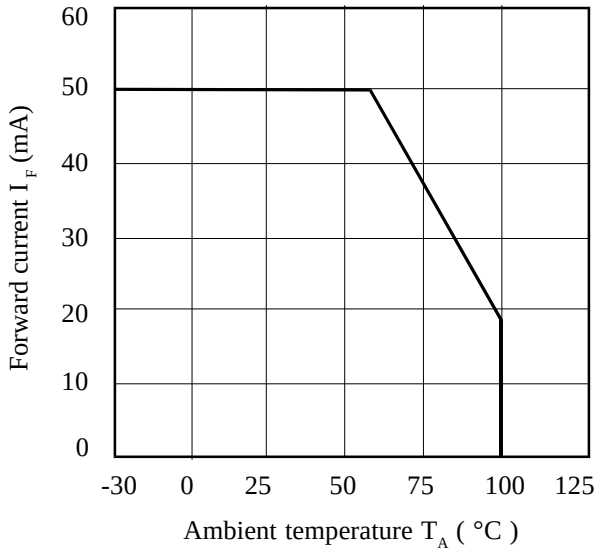
Collector Power Dissipation vs. Ambient Temperature



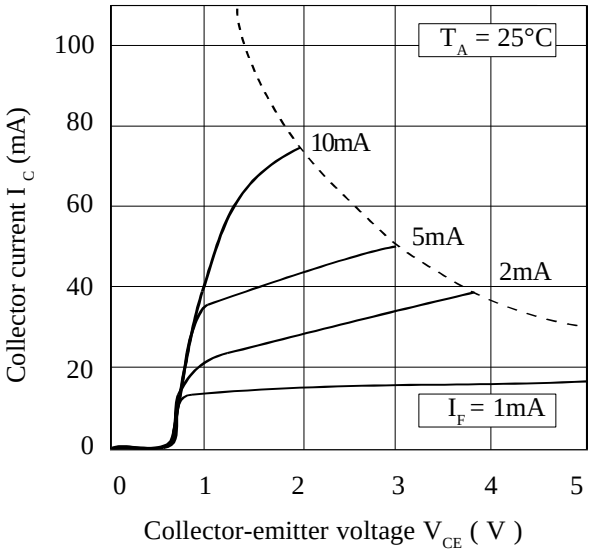
Collector-emitter Saturation Voltage vs. Forward Current



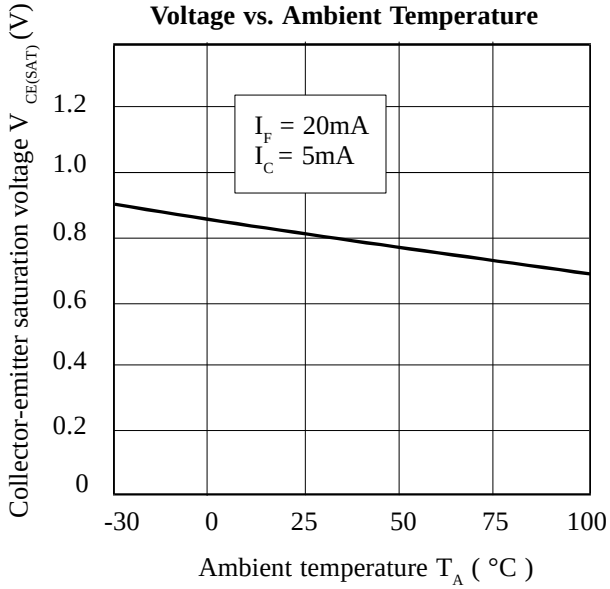
Forward Current vs. Ambient Temperature



Collector Current vs. Collector-emitter Voltage



Collector-emitter Saturation Voltage vs. Ambient Temperature



Relative Current Transfer Ratio vs. Ambient Temperature